

EPO-TEK® H70E-2

Technical Data Sheet For Reference Only

Thermally Conductive, Electrically Insulating Epoxy

Date: February 2022

Rev: X
No. of Components: Two
Mix Ratio by Weight: 1:1

Specific Gravity: Part A: 1.50 Part B: 2.30

Pot Life: 2 Days

Shelf Life- Bulk: One year at room temperature

Shelf Life- Syringe: One year at -40°C

Recommended Cure: 150°C / 1 Hour

Minimum Alternative Cure(s):

May not achieve performance properties listed below

175°C / 1 Minute 150°C / 5 Minutes 120°C / 15 Minutes

80°C / 90 Minutes

NOTES:

• Container(s) should be kept closed when not in use.

• Filled systems should be stirred thoroughly before mixing and prior to use.

• Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages.

<u>Product Description:</u> EPO TEK® H70E-2 is a two component, thermally conductive electrically insulating epoxy designed for glob-top chip protection in TAB and COB die-attach technologies. It is used to prevent chips from being mechanically damaged during micropackage assembly and handling.

<u>Typical Properties:</u> Cure condition: 150°C / 1 Hour Different batches, conditions & applications yield differing results.

Data below is not guaranteed. To be used as a guide only, not as a specification. * denotes test on lot acceptance basis

PHYSICAL PROPERTIES:						
* Color (before cure):		Part A	A: Black Pa	art B: C	Cream	
* Consistency:	Smooth thixotropic			paste		
* Viscosity (23°C) @ 20 rpm:		9,0	000 - 15,000	cPs		
Thixotropic Index:			1.7			
* Glass Transition Temp:			≥ 80	°C (D	ynamic Cure: 20-200°C/ISO 25 Min; Ramp -10-200°C @20°C/Min)	
Coefficient of Thermal Expansion (CTE):						
	Below Tg:		20		in/in°C	
	Above Tg:		112	x 10 ⁻⁶	in/in°C	
Shore D Hardness:			65			
Lap Shear @ 23°C:			> 2,000	psi		
Die Shear @ 23°C:			≥ 5	Kg	1,778 psi	
Degradation Temp:			447	°C		
Weight Loss:						
	@ 200°C:		0.10	%		
	@ 250°C:		0.30	%		
	@ 300°C:		0.70	%		
Suggested Operating Temperature:			< 300	. `	°C (Intermittent)	
Storage Modulus:			1,214,415	psi		
Ion Content:		Cl⁻:	267 ppm			
* Particle Size:			≤ 50	micro	ons	

ELECTRICAL AND THERMAL PROPERTIES:		
Thermal Conductivity:	1.0	W/mK
Volume Resistivity @ 23°C:	$\geq 8 \times 10^{12}$	Ohm-cm
Dielectric Constant (1KHz):	5.19	
Dissipation Factor (1KHz):	0.007	

Epoxies and Adhesives for Demanding Applications™

This information is based on data and tests believed to be accurate. Epoxy Technology, Inc. makes no warranties (expressed or implied) as to its accuracy and assumes no liability in connection with any use of this product.

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EPO-TEK® H70E-2 Advantages & Suggested Application Notes:

- The epoxy exhibits resistance against moisture, contamination and solvents which make
 it an ideal glob top. See Technical Paper #24 in our library for process flow in TAB
 packaging and reliability study http://www.epotek.com/technical-papers.asp.
- A slightly thixotropic paste with excellent handling characteristics, pot life and short curing cycles. The rheology provides a dot-shape or dome configuration over wire-bonded die. Capable of glob-top DAM-and-FILL, or single-dot glob-top.
- Suitable for mass production as semiconductor encapsulant; low temp cure 80°C capable, controlled viscosity. Capable of many packages including TAB, COB, CSPs, BGAs, DIP and TO-cans.
- Excellent adhesion to PCB, ferrous and non-ferrous metals, glass, ceramic, epoxy package shells and semiconductor materials.
- Recommended for chip bonding, circuit repair, reinforce lead-frames, LSI chip packaging and good heat dissipation.